Supporting Information

Ambient Pressure Synthesis of Unstable Bulk Phases of Strongly Correlated Rare-Earth Nickelates

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	Figure	Rp (%)	Rwp (%)	Chi^2
SmNiO _x - As synthesized	1d	6.20	9.26	6.75
SmNiO _x - RT aged	3a	5.28	7.55	4.54
SmNiO _x - HT aged	3b	4.79	6.87	4.00
NdNiO _x - As synthesized	1c	3.58	4.64	1.90
NdNiO _x -RT aged	2a	5.22	6.79	2.68
NdNiO _x -HT aged	2b	6.88	9.48	5.41

Table S1. Summary of the fitting results of the Rietveld refinement of XRD patterns reported in the manuscript.

Table S2. Summary of XPS fitting analysis of Ni $2p_{3/2}$ peak of NdNiO_x and SmNiO_x before and after aging done using the multiplet peaks of free Ni²⁺ and Ni³⁺ ions, as reported by Biesinger *et al.*

Peak ID	Energy (eV)	FWHM (eV)	%Area
Ni ²⁺ - 1	853.7	1.0	36.79
Ni ²⁺ - 2	855.7	2.25	8.5
Ni ³⁺ - 3	854.6	1.4	25.75
Ni ³⁺ - 4	855.3	1.5	4.85
Ni ³⁺ - 5	855.7	1.4	14.77
Ni ³⁺ - 6	856.5	1.4	9.32

SmNiOx- As synthesized

SmNiOx-Aged-RT

Peak ID		Energy (eV)	FWHM (eV)	%Area
Ni ²⁺ -	1	853.7	1.0	21.99
Ni ²⁺ -	2	855.7	2.25	0.019
Ni ³⁺ -	3	854.6	1.4	28.69
Ni ³⁺ -	4	855.3	1.5	17.2
Ni ³⁺ -	5	855.7	1.4	11.47
Ni ³⁺ -	6	856.5	1.4	20.63

NdNiOx- As synthesized

Peak ID		Energy (eV)	FWHM (eV)	%Area
Ni ²⁺ -	1	853.7	1.0	29.69
Ni ²⁺ -	2	855.7	2.25	1.49
Ni ³⁺ -	3	854.6	1.4	26.18
Ni ³⁺ -	4	855.3	1.5	12.67
Ni ³⁺ -	5	855.7	1.4	15.04
Ni ³⁺ -	6	856.5	1.4	14.92

NdNiOx- Aged-RT

Peak ID	Energy (eV)	FWHM (eV)	%Area
Ni ²⁺ - 1	853.7	1.0	27.33

Ni ²⁺ - 2	855.7	2.25	0.85
Ni ³⁺ - 3	854.6	1.4	33.79
Ni ³⁺ - 4	855.3	1.5	8.55
Ni ³⁺ - 5	855.7	1.4	15.98
Ni ³⁺ - 6	856.5	1.4	13.49



Figure S1. Valence band XPS spectrum of $NdNiO_x$ before and after RT-ageing. In both samples, the VB edge close to the E_F position indicates that both samples are p-type semiconductors.